

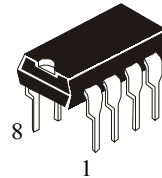
ILC555

CMOS general purpose timer

The ILC555 is CMOS RC timers providing significantly improved performance over the standard SE/NE555 and 355 timers, while at the same time being direct replacements for those devices in most applications. Improved parameters include low supply current, wide operating supply voltage range, low THRESHOLD, TRIGGER and RESET currents, no crowbarbing of the supply current during output transitions, higher frequency performance and no requirement to decouple CONTROL VOLTAGE for stable operation.

Specifically, the ILC555 is stable controller capable of producing accurate time delays of frequencies.

- Exact equivalent in most cases for SE/NE555.
- Low Supply Current.
- High speed operation – 500 kHz guaranteed.
- Wide operation supply voltage range – 2 to 18 volts.
- Timing from microseconds through hours.
- Operates in both astable and monostable modes.
- Adjustable duty cycle.
- High output source/sink driver can drive TTL/CMOS



N SUFFIX
PLASTIC

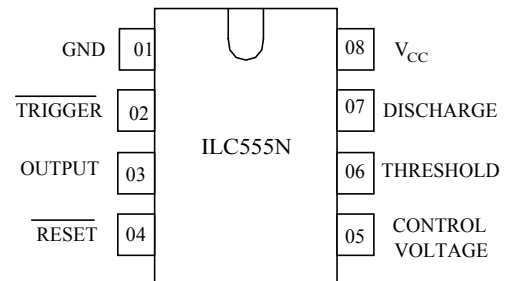
ORDERING INFORMATION

ILC555N Plastic

IZC555 Chip

$T_A = -20^\circ$ to 70° C for
the package

PIN ASSIGNMENT



TRUTH TABLE

THRESHOLD	TRIGGER	RESET	OUTPUT	DISCHARGE
X	X	L	L	ON
$> 2/3 \cdot V_{CC}$	$> 1/3 \cdot V_{CC}$	H	L	ON
$< 2/3 \cdot V_{CC}$	$> 1/3 \cdot V_{CC}$	H	STABLE	STABLE
X	$< 1/3 \cdot V_{CC}$	H	H	OFF

MAXIMUM RATINGS AND RECOMMENDED OPERATING CONDITIONS

Parameter, unit	Symbol	Recommended operating conditions		Maximum ratings	
		Value		Value	
		min	max	min	max
Supply Voltage, V	V_{CC}	2.0	18.0	0	18.0
Output Current, mA	I_O	-	20	-	100
Input Voltage, V	$V_{TH}, V_{TRIG}, V_{RST}$	-	-	-0.3	$V_{CC}+0.3$
Power Dissipation, mW	P_D	-	-	-	200
Operating Temperature, °C	T_{OPR}	-20	70	-20	85
Storage Temperature, °C	T_{STG}	-	-	-65	150
Lead Temperature, 1 mm from Case for 10 Seconds, °C	T_{SOLDER}	-	-		260

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Parameter, units	Symbol	Test Conditions		Value		Temperature, °C
		I_{OL}, I_{OH}	V_{CC}, B	min	max	
Threshold Voltage, V	V_{TH}		5.0	0.65 V_{CC}	0.70 V_{CC}	25±10
				0.60 V_{CC}	0.80 V_{CC}	-20, 70
Trigger voltage, V	V_{TRIG}		5.0	0.31 V_{CC}	0.36 V_{CC}	25±10
				0.28 V_{CC}	0.40 V_{CC}	-20, 70
Reset voltage, V	V_{RST}		2.0	0.4	1.0	25±10
			18.0			
			2.0	0.2	1.5	-20, 70
			18.0			
Control Voltage Lead, V	V_{CV}			0.65 V_{CC}	0.69 V_{CC}	25±10
				0.60 V_{CC}	0.80 V_{CC}	-20, 70
Output voltage Low, V	V_{OL}	$I_{OL} = 3.2 \text{ mA}$	5.0		0.4	25±10
		$I_{OL} = 20 \text{ mA}$	15.0		1.0	
		$I_{OL} = 3.2 \text{ mA}$	5.0		0.6	-20, 70
		$I_{OL} = 20 \text{ mA}$	15.0		1.5	
Output voltage High, V	V_{OH}	$I_{OH} = -0.8 \text{ mA}$	5.0	4.0		25±10
			15.0	14.3		
			5.0	3.5		-20, 70
			15.0	14.0		
Supply Current, μA	I_{CC}		2.0		200	25±10
			18.0		300	
			2.0		400	-20, 70
			18.0		600	

AC ELECTRICAL CHARACTERISTICS

Parameter, unit	Symbol	Test Conditions		Value		Tempe- rature, °C
		R _L , C _L	V _{CC} , V	Min	Max	
Rise (Fall) Time of Output, ns	t _{THL} , t _{TLH}	R _L = 10 MΩ, C _L = 10 pF	5.0	35	75	25±10
				70	150	-20, 70
Guaranteed Max Osc Freq, kHz	f _{MAX}	Astable Operation	2.0- 18.0	500		25±10
				200		-20, 70
Initial accuracy, %		R _L = 1 - 100 kΩ, C _L = 0.1 μF		5		
Drift with Temperature, %/°C	αf		5.0		0.02	-20, 70
			10.0		0.03	
			15.0		0.06	
Drift with Supply Voltage, %/B	Δf		5.0		3	25±10
					6	-20, 70

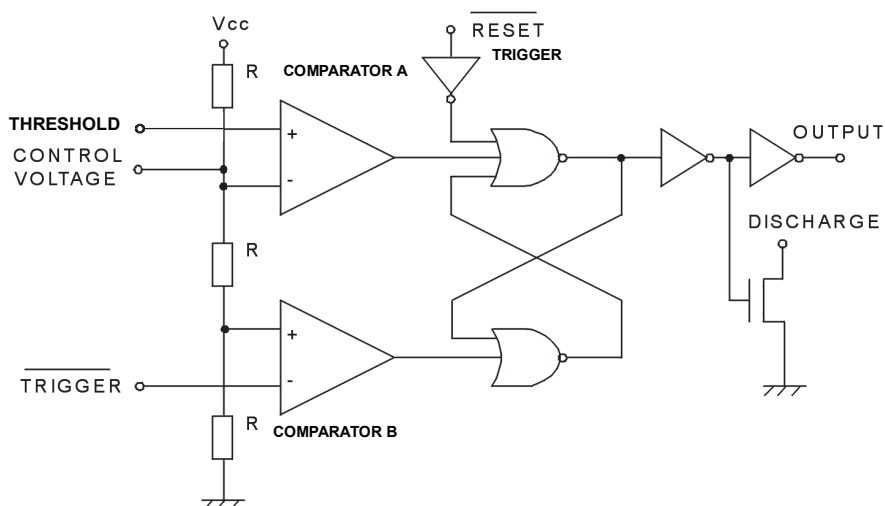


Figura 1. Block Diagram

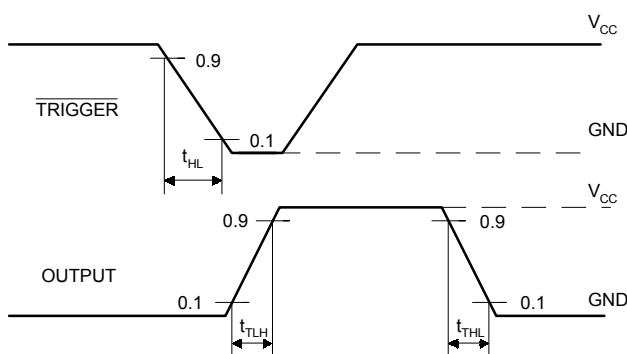
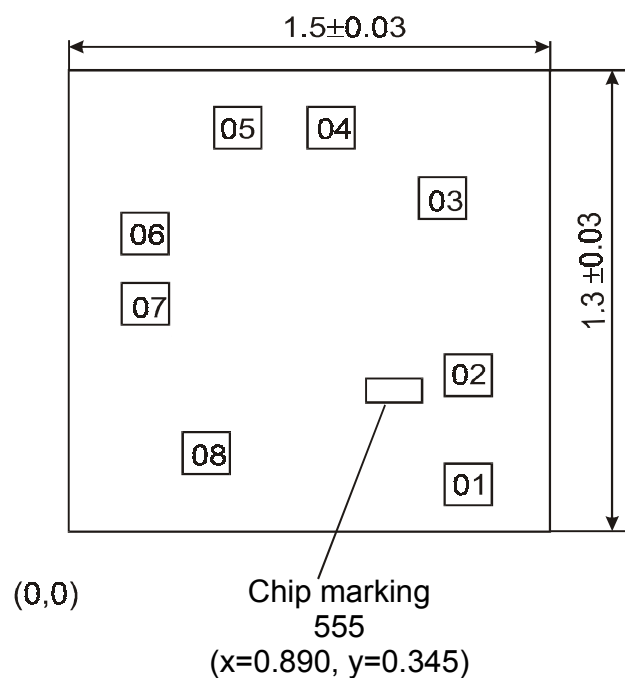


Figura 2. Switching Waveforms

CHIP PAD DIAGRAM IZC555



Pad size 0.110 x 0.110 mm (Pad size is given as per passivation layer)

Thickness of chip 0.46 ± 0.02 mm

PAD LOCATION

Pad No	Symbol	X	Y
01	GND	1.2840	0.1160
02	$\overline{\text{Trigger}}$	1.2840	0.4410
03	Output	1.2815	1.0545
04	$\overline{\text{Reset}}$	0.8870	1.0840
05	Control Voltage	0.3335	1.0840
06	Threshold	0.1160	0.9995
07	Discharge	0.1160	0.7965
08	Vcc	0.1760	0.1270